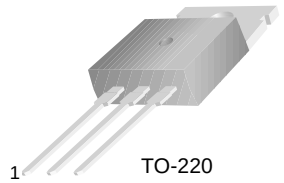
FAIRCHILD
SEMICONDUCTOR®

KSE5740/5741/5742

High Voltage Power Switching In Inductive Circuits

- High Voltage Power Darlington TR
- Small Engine Ignition
- Switching Regulators
- Inverters
- Solenold and Relay Drivers
- Motor Control



TO-220

1.Base 2.Collector 3.Emitter

NPN Silicon Darlington Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
BV_{CEO}(sus)	Collector-Emitter Sustaining Voltage		
	: KSE5740	300	V
	: KSE5741	350	V
	: KSE5742	400	V
V_{CEV}	Collector-Emitter Voltage : KSE5740	600	V
	: KSE5741	700	V
	: KSE5742	800	V
V_{EBO}	Emitter-Base Voltage	8	V
I_C	Collector Current (DC)	8	A
I_{CP}	*Collector Current (Pulse)	16	A
I_B	Base Current (DC)	2.5	A
I_{BP}	*Base Current (Pulse)	5	A
P_C	Collector Dissipation	80	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{CEO}(sus)	Collector-Emitter Sustaining Voltage					
	: KSE5740	I_C = 50mA, I_B=0	300			V
	: KSE5741		350			V
	: KSE5742		400			V
I_{CEV}	Collector Cut-off Current	V_{CEV}=Rate Value, $V_{BE(OFF)}$=1.5V			1	mA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 8V, I_C= 0			75	mA
h_{FE}	DC Current Gain	V_{CE} =5V, I_C = 0.5A	50	100		
		V_{CE} =5V, I_C = 4A	200	400		
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C =4A, I_B = 0.2A			2	V
		I_C =8A, I_B= 0.4A			3	V
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C =4A, I_B = 0.2A			2.5	V
		I_C =8A, I_B = 0.4A			3.5	V
V_F	Diode Forward Voltage	I_F =5A			2.5	V
t_D	Delay Time	V_{CC} = 250V, I_C(pk) = 6A		0.04		µs
t_R	Rise Time	I_{B1} = I_{B2} = 0.25A		0.5		µs
t_S	Storage Time	t_P = 25µs		8		µs
t_F	Fall Time	Duty Cycle≤1%		2		µs
t_{SV}	Voltage Storage Time	I_C(pk) = 6A, V_{CE}(pk) = 250V		4		µs
t_C	Cross-over Time	I_B1= 0.06A, V_{BE} (off) = 5V		2		µs

* PW=5ms, Duty Cycle=10%

Typical Characteristics

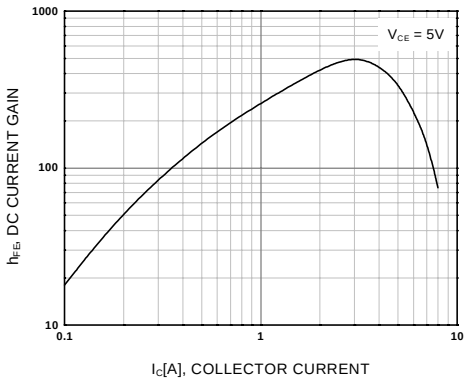


Figure 1. DC current Gain

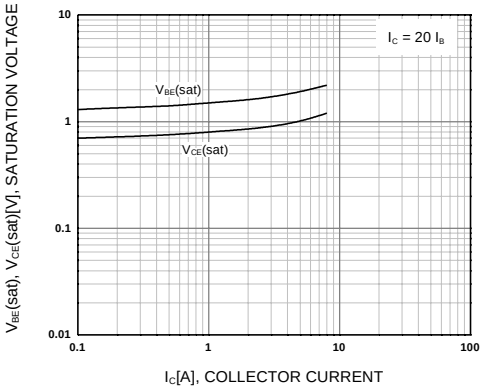


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

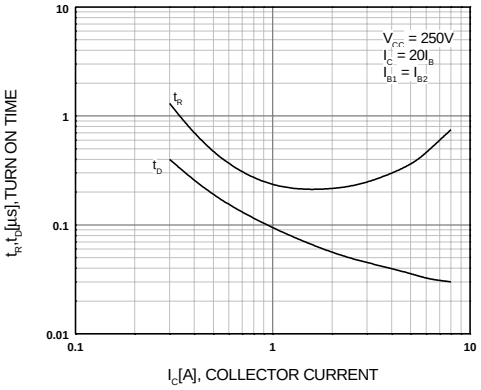


Figure 3. Turn On Time

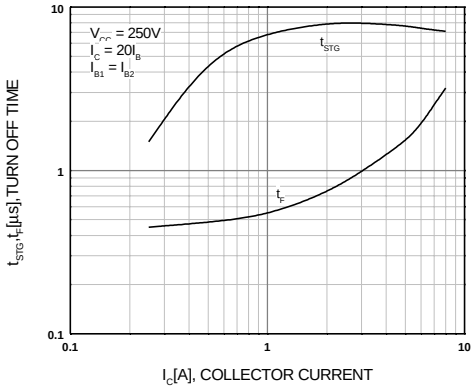


Figure 4. Turn Off Time

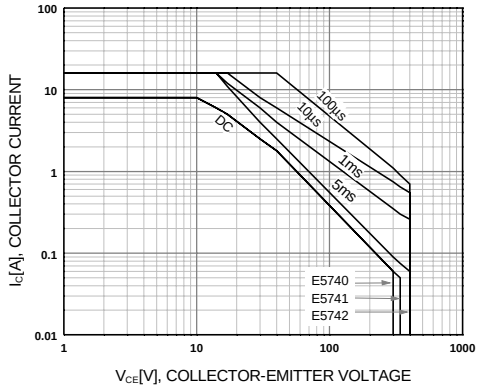


Figure 5. Safe Operating Area

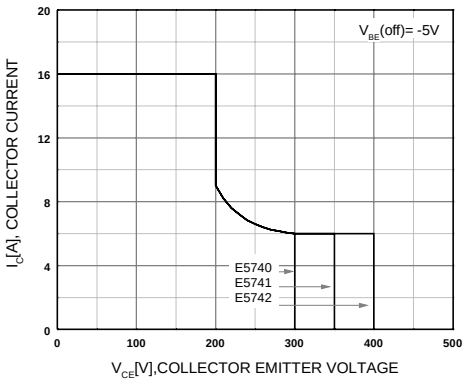


Figure 6. Reverse Bias Safe Operating Area

Typical Characteristics (Continued)

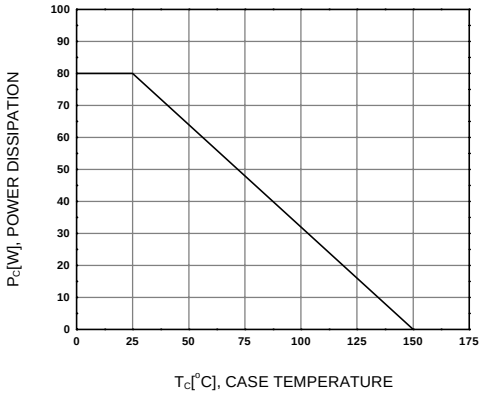
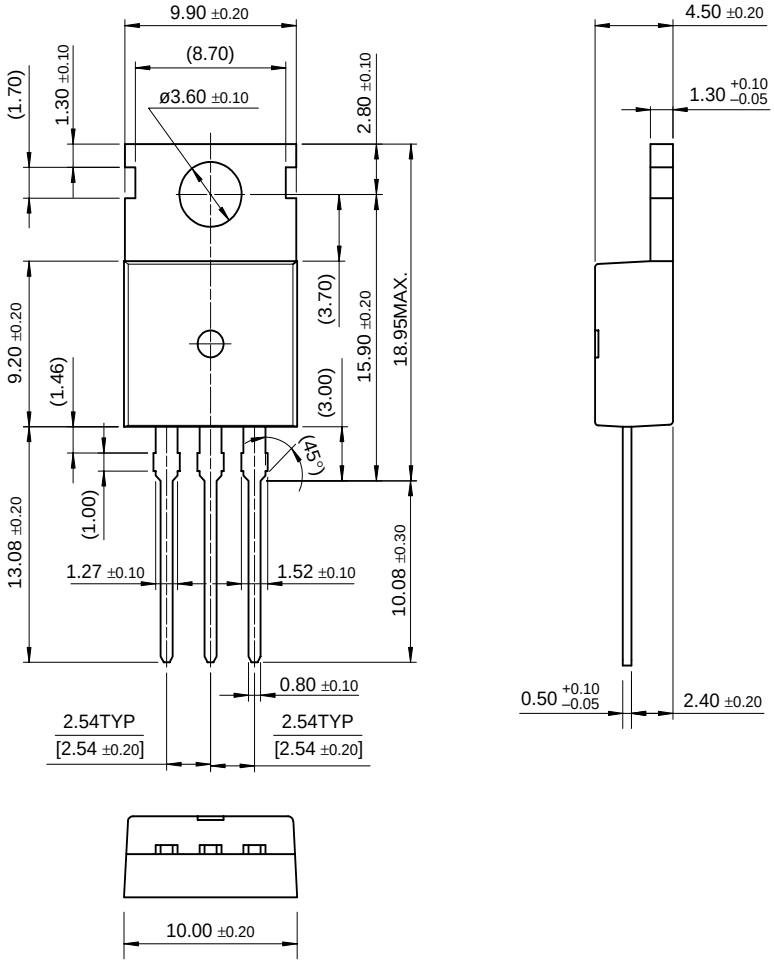


Figure 1. Power Derating

Package Demensions

TO-220



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™
Bottomless™
CoolFET™
CROSSVOLT™
DenseTrench™
DOME™
EcoSPARK™
E^2CMOS™
EnSigna™
FACT™
FACT Quiet Series™
FAST®
FASTr™
FRFET™
GlobalOptoisolator™
GTO™
HiSeC™
ISOPLANAR™
LittleFET™
MicroFET™
MICROWIRE™
OPTOLOGIC™
OPTOPLANAR™
PACMAN™
POP™
Power247™
PowerTrench®
QFET™
QS™
QT Optoelectronics™
Quiet Series™
SLIENT SWITCHER®
SMART START™
STAR*POWER™
Stealth™
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SyncFET™
TruTranslation™
TinyLogic™
UHC™
UltraFET®
VCX™

STAR*POWER is used under license

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.